# Single 2-Input AND Gate

The NL17SG08 MiniGate<sup>™</sup> is an advanced high-speed CMOS 2-input AND gate in ultra-small footprint.

The NL17SG08 input structures provides protection when voltages up to 4.6 V are applied.

### Features

- Wide Operating V<sub>CC</sub> Range: 0.9 V to 3.6 V
- High Speed:  $t_{PD} = 2.5$  ns (Typ) at  $V_{CC} = 3.0$  V,  $C_L = 15$  pF
- Low Power Dissipation:  $I_{CC} = 0.5 \ \mu A$  (Max) at  $T_A = 25^{\circ}C$
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb–Free and Halide–Free Devices

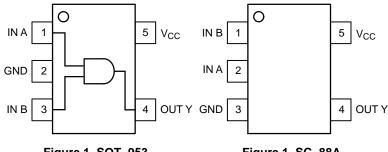


Figure 1. SOT-953 (Top Thru View)

Figure 1. SC-88A (Top View)

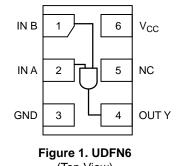




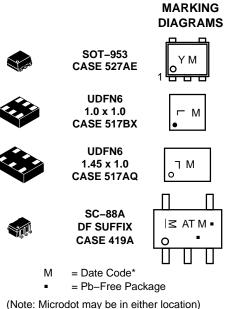


Figure 2. Logic Symbol



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\*Date Code orientation and/or position may vary depending upon manufacturing location.

### **PIN ASSIGNMENT**

PIN	SOT-953	SC-88A	UDFN6
1	IN A	IN B	IN B
2	GND	IN A	IN A
3	IN B	GND	GND
4	OUT Y	OUT Y	OUT Y
5	V <sub>CC</sub>	V <sub>CC</sub>	VC
6	_	_	V <sub>CC</sub>

### **FUNCTION TABLE**

Inp	uts	Output
Α	в	Y
L	L	L
L	н	L
н	L	L
Н	Н	н

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

### MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +5.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +4.6	V
V <sub>OUT</sub>	DC Output Voltage	Output at High or Low State Power–Down Mode ( $V_{CC} = 0 V$ )	-0.5 to V <sub>CC</sub> +0.5 -0.5 to +4.6	V
Ι <sub>ΙΚ</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
Ι <sub>ΟΚ</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±20	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin		±20	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin		±20	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		+150	°C
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
$V_{ESD}$	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3)	>2000 >100	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

Tested to EIA/JESD22–A114–A.
 Tested to EIA/JESD22–A115–A.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Characteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	0.9	3.6	V
V <sub>IN</sub>	Digital Input Voltage	0.0	3.6	V
V <sub>OUT</sub>	Output Voltage Output at High or Low State Power–Down Mode (V <sub>CC</sub> = 0 V)	0.0 0.0	V <sub>CC</sub> 3.6	V
T <sub>A</sub>	Operating Temperature Range	-55	+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fail Rate $$V_{CC}$$ = 3.3 V $\pm$ 0.3 V	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

### DC ELECTRICAL CHARACTERISTICS

		T <sub>A</sub> = 25°C		25°C	Τ <sub>Α</sub> -55°C to	∖ = o +125°C			
Symbol	Parameter	C	onditions	V <sub>CC</sub> (V)	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input			0.9	V <sub>CC</sub>		V <sub>CC</sub>		V
	Voltage		1.1 to 1.3	0.7xV <sub>CC</sub>		0.7xV <sub>CC</sub>			
				1.4 to 1.6	$0.65 \mathrm{xV}_{\mathrm{CC}}$		$0.65 \mathrm{xV}_{\mathrm{CC}}$		
				1.65 to 1.95	$0.65 \mathrm{xV}_{\mathrm{CC}}$		$0.65 \mathrm{xV}_{\mathrm{CC}}$		
				2.3 to 2.7	1.7		1.7		
				3.0 to 3.6	2.0		2.0		
VIL	Low-Level Input			0.9		GND		GND	V
	Voltage			1.1 to 1.3		0.3xV <sub>CC</sub>		0.3xV <sub>CC</sub>	
				1.4 to 1.6		0.35xV <sub>CC</sub>		0.35xV <sub>CC</sub>	
				1.65 to 1.95		0.35xV <sub>CC</sub>		0.35xV <sub>CC</sub>	
				2.3 to 2.7		0.7		0.7	
				3.0 to 3.6		0.8		0.8	
V <sub>OH</sub>	High-Level	V <sub>IN</sub> =	I <sub>OH</sub> = -20 μA	0.9	0.75		0.75		V
	Output Voltage	V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -0.3 mA	1.1 to 1.3	0.75xV <sub>CC</sub>		0.75xV <sub>CC</sub>		
			I <sub>OH</sub> = -1.7 mA	1.4 to 1.6	0.75xV <sub>CC</sub>		0.75xV <sub>CC</sub>		
			I <sub>OH</sub> = -3.0 mA	1.65 to 1.95	Vcc-0.45		Vcc-0.45		
			I <sub>OH</sub> = -4.0 mA	2.3 to 2.7	2.0		2.0		
			I <sub>OH</sub> = -8.0 mA	3.0 to 3.6	2.48		2.48		
V <sub>OL</sub>	Low-Level	V <sub>IN</sub> =	I <sub>OL</sub> = 20 μA	0.9		0.1		0.1	V
	Output Voltage	V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 1.1 mA	1.1 to 1.3		0.25xV <sub>CC</sub>		0.25xV <sub>CC</sub>	
		I <sub>OL</sub> = 1.7 mA	1.4 to 1.6		0.25xV <sub>CC</sub>		0.25xV <sub>CC</sub>		
			I <sub>OL</sub> = 3.0 mA	1.65 to 1.95		0.45		0.45	
			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7		0.4		0.4	
			I <sub>OL</sub> = 8.0 mA	3.0 to 3.6		0.4		0.4	
I <sub>IN</sub>	Input Leakage Current	0 ≤ V <sub>IN</sub> ≤ 3.6 V		0 to 3.6		±0.1		±1.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =	V <sub>CC</sub> or GND	3.6		0.5		10.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### NL17SG08

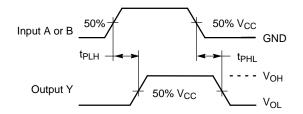
Symbol	Parameter	Test Condition	V <sub>CC</sub> (V)	-	T <sub>A</sub> = 25° (	0		∖ = o +125°C							
				Min	Тур	Max	Min	Max	Unit						
t <sub>PLH</sub> ,	Propagation Delay,	$C_{L} = 10 \text{ pF},$	0.9	-	10.0	12.4	-	14.8	ns						
t <sub>PHL</sub>	A or B to Y	$R_L = 1 M\Omega$	1.1 to 1.3	-	8.0	10.7	-	13.6							
			1.4 to 1.6	-	5.9	9.6	-	11.3							
			1.65 to 1.95	-	4.5	7.0	-	7.5							
		-	2.3 to 2.7	-	2.9	4.4	-	4.9							
			3.0 to 3.6	-	2.2	3.5	-	4.1							
		$C_{L} = 15 \text{ pF},$	0.9	-	11.7	13.5	-	15.0	ns						
		R <sub>L</sub> = 1 ΜΩ	1.1 to 1.3	-	8.8	10.2	-	13.7							
			1.4 to 1.6	-	6.5	9.5	-	12.6							
								1.65 to 1.95	-	5.0	7.7	-	8.0		
								2.3 to 2.7	-	3.2	4.9	-	5.6		
								3.0 to 3.6	-	2.5	3.8	-	4.4		
		$C_{L} = 30 \text{ pF},$	0.9	-	13.0	16.0	-	19.0	ns						
		R <sub>L</sub> = 1 ΜΩ	$\kappa_{L} = 1 \text{ Ims}_{2}$	$\kappa_{L} = 1$ IVIS2	$\kappa_{\rm L} = 1.0052$	1.1 to 1.3	-	10.0	12.4	-	17.2				
							1.4 to 1.6	-	8.9	11.8	-	14.9			
													1.65 to 1.95	-	6.9
			2.3 to 2.7	-	4.4	6.4	-	6.8							
			3.0 to 3.6	-	3.5	4.9	-	5.4							
C <sub>IN</sub>	Input Capacitance		0 to 3.6		3	-	-	-	pF						
C <sub>PD</sub>	Power Dissipation Capacitance (Note 4)	f = 10 MHz	0.9 to 3.6	-	4	-	-	-	pF						

### **AC ELECTRICAL CHARACTERISTICS** (Input $t_r = t_f = 3.0 \text{ ns}$ )

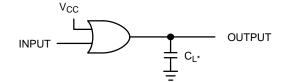
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

 4. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

### **NL17SG08**







\*Includes all probe and jig capacitance. A 1–MHz square input wave is recommended for propagation delay tests.



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NL17SG08P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel
NL17SG08DFT2G	SC–88A (Pb–Free)	3000 / Tape & Reel
NLV17SG08DFT2G*	SC–88A (Pb–Free)	3000 / Tape & Reel
NL17SG08AMUTCG	UDFN6 1.45x1 mm (Pb-Free)	3000 / Tape & Reel
NL17SG08CMUTCG	UDFN6 1x1 mm (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.

# **NSEM**



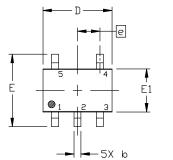
### SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

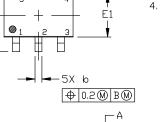
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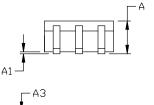
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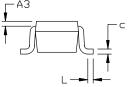
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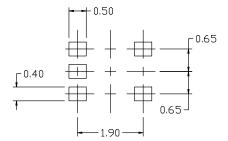
DATE 11 APR 2023











#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS			
MIU	MIN.	NDM.	MAX.	
A	0.80	0.95	1.10	
A1			0.10	
A3	0.20 REF			
b	0.10	0.20	0.30	
С	0.10		0.25	
D	1.80	2.00	5'50	
E	2.00	2.10	5'50	
E1	1.15	1.25	1.35	
e	0.65 BSC			
L	0.10	0.15	0.30	

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

### **GENERIC MARKING**





\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
DOCUMENT NUMBER:	98ASB42984B			ot when accessed directly from when stamped "CONTROLLED (	
DESCRIPTION: SC-88A (SC-70-5/SOT-353)					PAGE 1 OF 1

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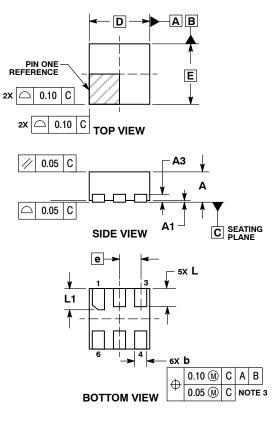
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- M = Date Code
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# DUSem



SCALE 4:1



UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

### DATE 18 MAY 2011

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN A DE ADD & OR MULTICAL TERMINAL TR
- AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FL					
	MILLIN	IETERS			
DIM	MIN	MAX			
Α	0.45	0.55			
A1	0.00	0.05			
A3	0.13	0.13 REF			
b	0.12	0.22			
D	1.00	BSC			
E	1.00 BSC				
е	0.35 BSC				
L	0.25	0.35			
L1	0.30	0.40			

### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### GENERIC **MARKING DIAGRAM\***



X = Specific Device Code M = Date Code

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SCALE 4:1

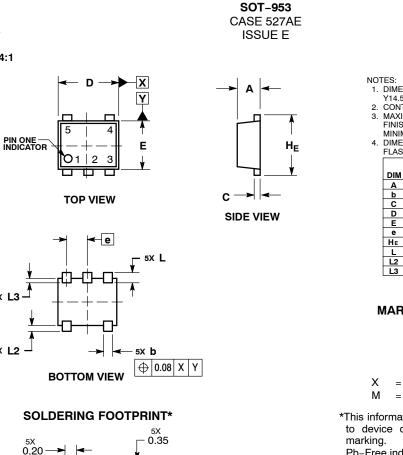
5X L3

5X L2

PACKAGE OUTLINE

0.35 PITCH





#### DATE 02 AUG 2011

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	0.34	0.37	0.40
b	0.10	0.15	0.20
С	0.07	0.12	0.17
D	0.95	1.00	1.05
E	0.75	0.80	0.85
е	0.35 BSC		
ΗE	0.95	1.00	1.05
L	0.175 REF		
L2	0.05	0.10	0.15
L3			0.15

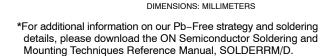
## GENERIC **MARKING DIAGRAM\***

= Specific Device Code

= Month Code

\*This information is generic. Please refer to device data sheet for actual part

Pb-Free indicator, "G" or microdot " .", may or may not be present.



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1.20

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